Directional Emission and Universal Far-Field Behavior from Semiconductor Lasers with Limacon-Shaped Microcavity

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Directional emission and universal far-field behavior from semiconductor lasers with limaçon-shaped microcavity

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We report experimental demonstration of directional light emission from limaçon-shaped microcavity semiconductor lasers. Quantum cascade lasers (QCLs) emitting at λ= 10 μm are used as a model system. Both ray optics and wave simulations show that for deformations in the range 0.37 < ε < 0.43, these microcavities support high quality-factor whispering gallerylike modes while having a directional far-field profile with a beam divergence θ1 ≈ 33° in the plane of the cavity. The measured far-field profiles are in good agreement with simulations. While the measured spectra show a transition from whispering gallerylike modes to a more complex mode structure at higher pumping currents, the far field is insensitive to the pumping current demonstrating the predicted “universal far-field behavior” of this class of chaotic resonators. Due to their relatively high quality factor, our microcavity lasers display reduced threshold current densities compared to conventional ridge lasers with millimeter-long cavities. The performance of the limaçon-shaped QCLs is robust with respect to variations of the deformation near its optimum value of ε= 0.40. © 2009 American Institute of Physics. [DOI: 10.1063/1.3153276]

Microcavity lasers have attracted a lot of attention in recent years due to the simplicity of their fabrication and low threshold currents, which makes them suitable for high-density optoelectronic integration.1 Microdisk lasers have low threshold current densities but their optical power output is very low due to total internal reflection of the whispering gallery modes (WGMs) and their far-field profiles are isotropic. Such properties limit their potential applications.

To overcome the intrinsic problems of microdisk lasers, various types of deformed structures2–4 were proposed, and/or demonstrated in a variety of gain media including polymers and semiconductors. Among these, electrically pumped semiconductor microcavity lasers such as stadium-shaped lasers,5 bow-tie lasers,6 and spiral-shaped lasers7–9 are of special interest for potential applications and as tools to study ray and wave chaos. Up to now, however, very few studies of microcavities in both experiment10 and theory11,12 have shown promise of achieving directional emission while having high quality-factor (Q-factor) modes in the cavity.

Recently, a limaçon-shaped microcavity has been proposed13 as a promising resonator shape for microcavity lasers with attractive properties such as a directional emission and a high cavity Q-factor. In this work, we fabricated λ= 10 μm quantum cascade lasers (QCLs) with limaçon-shaped microcavity and characterized their performance. We observed directional emission from our devices with a far-field divergence angle θ1 ≈ 33° in the plane of the cavity and a Q-factor of more than 1000 at the midinfrared wavelength. The measured far-field profiles of our devices are in excellent agreement with simulations.

The boundary of a limaçon microcavity is defined in polar coordinate as R(θ)= R0(1+ ε cos θ) where ε is the deformation factor and R0 is the radius of curvature when θ= π/2 [see the inset of Fig. 1(a)]. In this work, we first carried out wave simulations based on the boundary element method13 to study the effect of the parameter ε on the key characteristics of the limaçon microcavity QCLs such as Q-factor and directionality of the light emission. Note that the polarization of QCL is transverse magnetic (TM) due to the selection rules of the optical transition. The effective refractive index of our QCL material (lattice matched Ga0.47In0.53As/Al0.48In0.52As/InP) for TM polarization, n, is estimated to be 3.2, calculated from spectral measurement of the mode spacing of a Fabry–Pérot type ridge laser. Figures 1(a)–1(c) show the intensity distribution of some TM modes calculated for a structure with ε=0.40 and R0=80 μm. The two highest Q-factor modes are shown, respectively, in Figs. 1(a) and 1(b); they both have a calculated Q-factor >107, assuming no material loss in the laser cavity. Since these WGMs have the highest Q-factor, they can be excited at pumping currents just above the lasing threshold. The mode in Fig. 1(c) is a non-WGM which has a lower Q-factor of about 18 000 and as such we expect this type of mode will be excited at higher pumping currents. Figure 1(d) shows the Poincaré surface of section (SOS) of rays leaving the limaçon cavity with ε=0.4 and R0=80 μm calculated with ray optics simulations (see Ref. 13 for details). The character

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the cavity circumference each reflection at the cavity boundary. 30 000 rays are started along the Limacon cavity where \( s / H_{20849} \) regions A, B, C, and D, respectively, as marked in Fig. 1. The rays are followed until they cross the critical lines of the unstable manifold which determines the far-field pattern of the cavity. The highest far-field divergence angle of about 30° is measured from the \( 2 \)-factor \( WGM \); the inset is the external intensity distribution of the mode in Fig. 1. This device has a smaller threshold current density compared at similar wavelengths. 16,18 This is assigned to material and device processing improvements and to the limaçon resonator shape versus current (\( L-I \)) and voltage versus current (\( V-I \)) characteristics of a representative device with \( \varepsilon =0.40 \) and \( R_0=80 \) \( \mu m \). Peak output power of 4 mW, a threshold current density around 2.0 \( \text{KA/cm}^2 \), and a maximum slope efficiency of about 12 \( \text{mW/A} \) were obtained. This device has a smaller threshold current density compared with that (\( \sim 2.6 \text{ KAM/cm}^2 \)) of ridge QCLs with a length of 2.5 mm and 14 \( \mu m \) width processed from the same wafer. The slope efficiency of the device is lower than that (\( \sim 100 \text{ mW/A} \)) of the ridge QCLs because not all of the pumping area of the limaçon microcavity is utilized for the output optical power generation (see Fig. 1) due to the presence of WGMs in the cavity. For this device, a \( Q \)-factor of approximately 1200 was obtained based on the measurements of the threshold current density and the gain coefficient. 16 Although the measured \( Q \)-factor is smaller than those of shorter wavelength semiconductor lasers as a result of increase in waveguide losses, it is larger than the \( Q \)-factors reported for other circular-shaped QCLs emitting at similar wavelengths. 16,18 This is assigned to material and device processing improvements and to the limaçon resonator geometry.
tor, which supports high $Q$-factor WGMs. We note that, due to the high optical losses associated with free carrier absorption at mid-infrared wavelength, the measured $Q$-factor in our devices is much smaller than the value obtained in simulations.

Figure 4(a) shows the emission spectra of the limaçon microcavity QCL measured at different pumping currents along the $\theta=0$ direction with a high-resolution Fourier transform infrared spectrometer. The laser operates in single mode at $\lambda \approx 10 \, \mu m$ at the threshold current of 380 mA. At a pumping current of 500 mA, two sets of optical modes appeared, indicated by red and blue arrows. It is reasonable to assume that they correspond to the two high $Q$-factor WGMs shown in Figs. 1(a) and 1(b), respectively. The average mode spacing of each set is approximately 6.0 $cm^{-1}$, which agrees very well with the calculated value (6.2 $cm^{-1}$) for WGMs, given by $1/(L^2 \pi n)$, where $L$ is the perimeter of the structure. At higher pumping current, several additional unequally spaced modes appeared, indicated by green arrows, corresponding to lower $Q$-factor modes (non-WGMs) of the type shown in Fig. 1(c). We also observed essentially the same spectra from all far-field lobes in different directions.

The far-field profiles of our devices were measured in steps of 0.5° using a setup described in Ref. 15. The experimental results for a device with an optimal (in terms of the far-field divergence angle) deformation $\varepsilon=0.40$ are shown in Fig. 4(b) for pumping currents of 500 and 710 mA, together with the ray optics simulations. Excellent agreement is achieved between experiment and simulation. Note that although non-WGMs appear at higher pumping current of 710 mA [see Fig. 4(a)], the far-field profile is essentially the same as the one pumped at 500 mA showing directional emission due to the universal far-field behavior predicted for this type of resonator. The measured FWHM of the main lobe of the far-field profile is $\sim 33°$. The measured divergence is also similar to the one reported for rational caustic resonator ($\sim 35°$) and that of Fabry–Pérot type ridge laser ($\sim 40°$).

Very good agreement between the calculated and the measured far-field profiles was also observed with $\varepsilon$ different from 0.4. We note, however, for $\varepsilon$ larger than 0.5, the geometry of the microcavity is such that WGMs are not supported anymore in the cavity. The device performance is also insensitive to the deformation in the range of $0.37<\varepsilon<0.43$ well within the fabrication resolution of photolithography for $R_0 = 80 \, \mu m$ devices.

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